# DSC2001

### Silicon NPN epitaxial planar type

#### For general amplification Complementary to DSA2001

#### Features

- $\bullet$  High forward current transfer ratio  $h_{FE}$  with excellent linearity
- Low collector-emitter saturation voltage  $V_{CE(sat)}$
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL: Level 1 compliant)

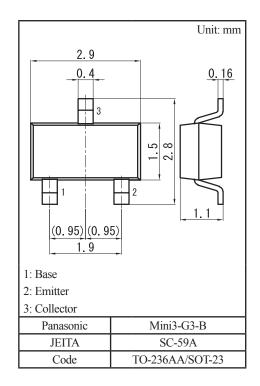
#### Marking Symbol: C1

#### Packaging

DSC2001×0L Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$

| Parameter                             | Symbol           | Rating      | Unit |
|---------------------------------------|------------------|-------------|------|
| Collector-base voltage (Emitter open) | V <sub>CBO</sub> | 60          | V    |
| Collector-emitter voltage (Base open) | V <sub>CEO</sub> | 50          | V    |
| Emitter-base voltage (Collector open) | V <sub>EBO</sub> | 7           | V    |
| Collector current                     | I <sub>C</sub>   | 100         | mA   |
| Peak collector current                | I <sub>CP</sub>  | 200         | mA   |
| Collector power dissipation           | P <sub>C</sub>   | 200         | mW   |
| Junction temperature                  | Tj               | 150         | °C   |
| Operating ambient temperature         | T <sub>opr</sub> | -40 to +85  | °C   |
| Storage temperature                   | T <sub>stg</sub> | -55 to +150 | °C   |



#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

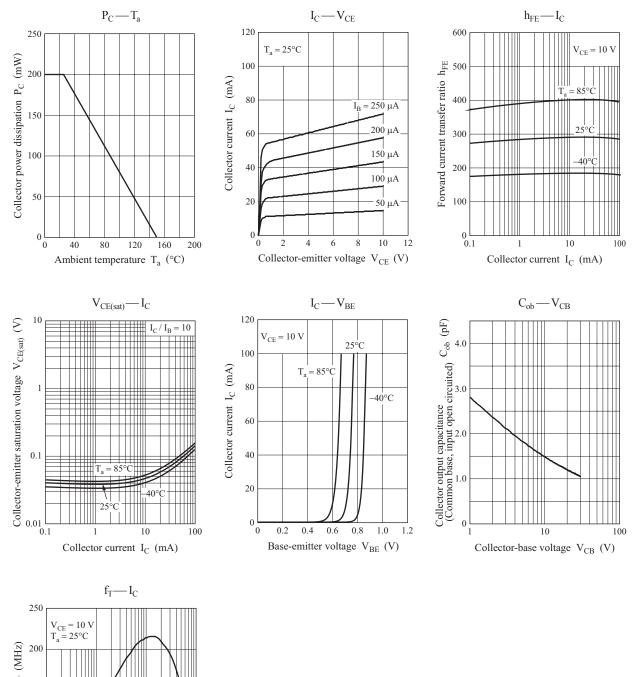
| Parameter   | Symbol                    | Conditions  | Min | Тур  | Max | Unit |
|---|---------------------------|---|-----|------|-----|------|
| Collector-base voltage (Emitter open)                               | V <sub>CBO</sub>          | $I_{\rm C} = 10 \ \mu {\rm A}, I_{\rm E} = 0$           | 60  |      |     | V    |
| Collector-emitter voltage (Base open)                               | V <sub>CEO</sub>          | $I_{\rm C} = 2  {\rm mA}, I_{\rm B} = 0$                | 50  |      |     | V    |
| Emitter-base voltage (Collector open)                               | V <sub>EBO</sub>          | $I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$                 | 7   |      |     | V    |
| Collector-base cutoff current (Emitter open)                        | I <sub>CBO</sub>          | $V_{CB} = 20 \text{ V}, I_E = 0$                        |     |      | 0.1 | μΑ   |
| Collector-emitter cutoff current (Base open)                        | I <sub>CEO</sub>          | $V_{CE} = 10 \text{ V}, I_B = 0$                        |     |      | 100 | μΑ   |
| Forward current transfer ratio *1                                   | h <sub>FE</sub>           | $V_{CE} = 10 \text{ V}, I_C = 2 \text{ mA}$             | 210 |      | 460 |      |
| Collector-emitter saturation voltage                                | V <sub>CE(sat)</sub>      | $I_{\rm C} = 100 \text{ mA}, I_{\rm B} = 10 \text{ mA}$ |     | 0.13 | 0.3 | V    |
| Transition frequency  | $\mathbf{f}_{\mathrm{T}}$ | $V_{CE} = 10 \text{ V}, I_C = 2 \text{ mA}$             |     | 150  |     | MHz  |
| Collector output capacitance<br>(Common base, input open circuited) | C <sub>ob</sub>           | $V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$     |     | 1.5  |     | pF   |

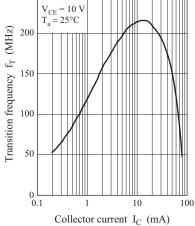
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*1: Rank classification

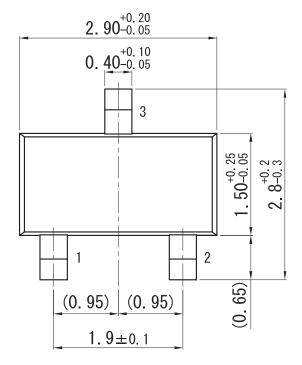
| Code           | R          | S          | 0          |  |
|----------------|------------|------------|------------|--|
| Rank           | R          | S          | No-rank    |  |
| $h_{\rm FE}$   | 210 to 340 | 290 to 460 | 210 to 460 |  |
| Marking Symbol | C1R        | C1S        | C1         |  |
|                |            |            |            |  |

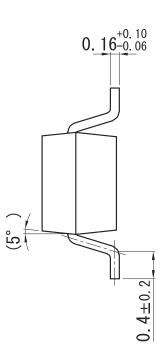
Product of no-rank is not classified and have no marking symbol for rank.

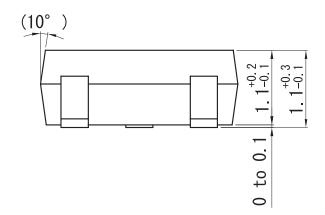




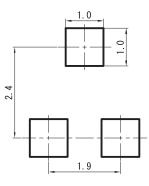
### Mini3-G3-B







Land Pattern (Reference) (Unit: mm)



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